

119TH CONGRESS
1ST SESSION

H. R. 6055

To amend the Internal Revenue Code of 1986 to extend the advanced manufacturing investment credit and include materials integral to semiconductor manufacturing.

IN THE HOUSE OF REPRESENTATIVES

NOVEMBER 17, 2025

Mr. FITZPATRICK (for himself, Mr. BOYLE of Pennsylvania, Mr. GOLDEN of Maine, and Ms. MCBRIDE) introduced the following bill; which was referred to the Committee on Ways and Means

A BILL

To amend the Internal Revenue Code of 1986 to extend the advanced manufacturing investment credit and include materials integral to semiconductor manufacturing.

1 *Be it enacted by the Senate and House of Representa-*
2 *tives of the United States of America in Congress assembled,*

3 **SECTION 1. SHORT TITLE.**

4 This Act may be cited as the “Strengthening Essen-
5 tial Manufacturing and Industrial Investment Act” or the
6 “SEMI Investment Act”.

1 **SEC. 2. EXPANSION AND EXTENSION OF ADVANCED MANU-**
 2 **FACTURING INVESTMENT CREDIT.**

3 (a) IN GENERAL.—Paragraph (3) of section 48D(b)
 4 of the Internal Revenue Code of 1986 is amended to read
 5 as follows:

6 “(3) ADVANCED MANUFACTURING FACILITY.—

7 “(A) IN GENERAL.—For purposes of this
 8 section, the term ‘advanced manufacturing fa-
 9 cility’ means a facility for which the primary
 10 purpose is the manufacturing of—

11 “(i) semiconductors,

12 “(ii) semiconductor manufacturing
 13 equipment, or

14 “(iii) semiconductor materials.

15 “(B) SEMICONDUCTOR MATERIALS.—

16 “(i) IN GENERAL.—For purposes of
 17 this paragraph, the term ‘semiconductor
 18 materials’ means—

19 “(I) any direct production mate-
 20 rial, or

21 “(II) any indirect production ma-
 22 terial,

23 which is used in semiconductor manufac-
 24 turing (as defined in section 231.116 of
 25 title 15, Code of Federal Regulations).

1 “(ii) DIRECT PRODUCTION MATE-
2 RIAL.—For purposes of this subparagraph,
3 the term ‘direct production material’
4 means a material which is—

5 “(I) primarily used for, and inte-
6 gral to, the production of a semicon-
7 ductor,

8 “(II) physically incorporated into
9 a finished semiconductor, and

10 “(III) any of the following:

11 “(aa) SUBSTRATE.—Any
12 substrate of silicon, silicon car-
13 bide, gallium nitride, gallium ar-
14 senide, indium phosphide, or
15 other semiconductor-grade sub-
16 strate material.

17 “(bb) THIN FILM OR
18 LAYERING MATERIAL.—Any de-
19 posited metal, dielectric, barrier
20 material, or dopant that forms
21 the physical structure of a semi-
22 conductor.

23 “(cc) PACKAGING SUB-
24 STRATE MATERIAL.—Any ce-
25 ramic, organic, or metallic mate-

1 rial that forms the physical base
2 for semiconductor packaging.

3 “(dd) BONDING, INTER-
4 CONNECT, OR ADHESIVE MATE-
5 RIAL.—Any wire bond, solder
6 bump, lead frame, die attach ad-
7 hesive, underfill, or other mate-
8 rial which—

9 “(AA) forms electrical
10 connections within a semi-
11 conductor, or

12 “(BB) provides struc-
13 tural integrity within a semi-
14 conductor.

15 “(iii) INDIRECT PRODUCTION MATE-
16 RIAL.—

17 “(I) IN GENERAL.—For purposes
18 of this subparagraph, the term ‘indi-
19 rect production material’ means a ma-
20 terial which is—

21 “(aa) a specialized material
22 that is primarily used for, and in-
23 tegral to, the production, testing,
24 inspection, or packaging of a
25 semiconductor,

“(bb) not physically incorporated into a finished semiconductor, and

“(cc) any of the following:

“(AA) PROCESS CHEMICALS.—An etchant, deposition precursor, doping gas, or other chemical used in wafer fabrication.

“(BB) PHOTOLITHOGRAPHY MATERIAL.—A photoresist, photoresist ancillary material, developer, mask, or pellicle used in semiconductor patterning.

“(CC) CLEANING, PLANARIZATION, AND PREPARATION MATERIAL.—A solvent, surfactant, slurry, Chemical Mechanical Planarization (CMP) pad, conditioning disk, or cleaning agent used to prepare and maintain semiconductor manufacturing surfaces.

1 “(DD) TESTING AND
2 INSPECTION MATERIAL.—A
3 probe card, test socket, or
4 optical inspection material.

5 “(EE) PACKAGING
6 PROCESS MATERIAL.—A
7 mold compound,
8 encapsulant, or bonding wire
9 used in assembly processes.

10 “(FF) FLUID-, GAS-,
11 OR WAFER-HANDLING MATE-
12 RIAL.—A polymer, elas-
13 tomer, ceramic material and
14 resultant tubings, fittings,
15 vessels, filters, seals, or
16 other such chemical-han-
17 dling or wafer-handling ma-
18 terial.

19 “(GG) WAFER PROC-
20 ESSING CHAMBER MATE-
21 RIALS.—Any process cham-
22 ber materials used in pro-
23 duction that play an active
24 role in energy transmission,
25 heat dissipation, plasma re-

1 sistance, or chemical resist-
2 ance.

3 “(HH) OTHER MATE-
4 RIAL.—Any other material
5 identified by the Secretary
6 pursuant to subclause (II).

7 “(II) OTHER INDIRECT PRODUC-
8 TION MATERIALS.—For purposes of
9 item (cc)(HH) of subclause (I), the
10 Secretary (in consultation with the
11 Secretary of Commerce) shall identify
12 additional materials which are de-
13 scribed in items (aa) and (bb) of such
14 subclause.

15 “(III) EXCLUSION.—The term
16 ‘indirect production material’ shall not
17 include any material which—

18 “(aa) has a generic use, and
19 “(bb) is predominately used
20 in an application other than
21 semiconductor manufacturing.

22 “(iv) LIST OF SEMICONDUCTOR MATE-
23 RIALS.—

24 “(I) IN GENERAL.—Not later
25 than 180 days after the date of enact-

1 ment of the Strengthening Essential
2 Manufacturing and Industrial Invest-
3 ment Act, and annually thereafter, the
4 Secretary, in consultation with the
5 Secretary of Commerce, shall publish
6 a list that sets forth the specifications,
7 characteristics, and applications of
8 materials that qualify as direct pro-
9 duction materials and indirect produc-
10 tion materials for purposes of clauses
11 (ii) and (iii).

12 “(II) PETITION FOR INTERIM DE-
13 TERMINATION.—In the case of any
14 material which has not been included
15 on the most recent list under sub-
16 clause (I), a taxpayer may file a peti-
17 tion (at such time, and in such form
18 and manner, as the Secretary may
19 prescribe) with the Secretary for a de-
20 termination of whether such material
21 qualifies as a direct production mate-
22 rial or indirect production material for
23 purposes of clauses (ii) and (iii).”.

1 (b) CREDIT PERIOD EXTENSION.—Section 48D(e) of
2 such Code is amended by striking “December 31, 2026”
3 and inserting “December 31, 2031”.

4 (c) EFFECTIVE DATE.—

5 (1) IN GENERAL.—Except as otherwise pro-
6 vided in this subsection, the amendments made by
7 this section shall apply to property placed in service
8 after the date of the enactment of this Act.

9 (2) CREDIT PERIOD EXTENSION.—The amend-
10 ment made by subsection (b) shall apply to property,
11 the construction of which begins after December 31,
12 2026.

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